

MMBT3906 TRANSISTOR (PNP)

FEATURES

- As complementary type the NPN transistor MMBT3904 is recommended
- Epitaxial planar die construction

MARKING: 2A

MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Value | Units |
|-----------------|--|-------------|-------|
| V_{CBO} | Collector-Base Voltage | -40 | V |
| V_{CEO} | Collector-Emitter Voltage | -40 | V |
| V_{EBO} | Emitter-Base Voltage | -5 | V |
| I_C | Collector Current -Continuous | -200 | mA |
| P_c | Total Device Dissipation | 200 | mW |
| $R_{\theta JA}$ | Thermal Resistance Junction to Ambient | 625 | °C/W |
| T_J | Junction Temperature | 150 | °C |
| T_{stg} | Storage Temperature | -55 to +150 | °C |

ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)

| Parameter | Symbol | Test conditions | MIN | MAX | UNIT |
|--------------------------------------|----------------------|---|-----|-------|---------------|
| Collector-base breakdown voltage | V_{CBO} | $I_C=-10\mu\text{A}, I_E=0$ | -40 | | V |
| Collector-emitter breakdown voltage | V_{CEO} | $I_C=-1\text{mA}, I_B=0$ | -40 | | V |
| Emitter-base breakdown voltage | V_{EBO} | $I_E=-10\mu\text{A}, I_C=0$ | -5 | | V |
| Collector cut-off current | I_{CBO} | $V_{CB}=-40\text{V}, I_E=0$ | | -0.1 | μA |
| Collector cut-off current | I_{CEX} | $V_{CE}=-30\text{V}, V_{BE(\text{off})}=-3\text{V}$ | | -50 | nA |
| Emitter cut-off current | I_{EBO} | $V_{EB}=-5\text{V}, I_C=0$ | | -0.1 | μA |
| DC current gain | $h_{FE(1)}$ | $V_{CE}=-1\text{V}, I_C=-10\text{mA}$ | 100 | 300 | |
| | $h_{FE(2)}$ | $V_{CE}=-1\text{V}, I_C=-50\text{mA}$ | 60 | | |
| | $h_{FE(3)}$ | $V_{CE}=-1\text{V}, I_C=-100\text{mA}$ | 30 | | |
| Collector-emitter saturation voltage | $V_{CE(\text{sat})}$ | $I_C=-50\text{mA}, I_B=-5\text{mA}$ | | -0.4 | V |
| Base-emitter saturation voltage | $V_{BE(\text{sat})}$ | $I_C=-50\text{mA}, I_B=-5\text{mA}$ | | -0.95 | V |
| Transition frequency | f_T | $V_{CE}=-20\text{V}, I_C=-10\text{mA}, f=100\text{MHz}$ | 300 | | MHz |
| Delay Time | t_d | $V_{CC}=-3\text{V}, V_{BE}=-0.5\text{V}$ | | 35 | nS |
| Rise Time | t_r | $I_C=-10\text{mA}, I_{B1}=-I_{B2}=-1\text{mA}$ | | 35 | nS |
| Storage Time | t_s | $V_{CC}=-3\text{V}, I_C=-10\text{mA},$ | | 225 | nS |
| Fall Time | t_f | $I_{B1}=-I_{B2}=-1\text{mA}$ | | 75 | nS |

CLASSIFICATION OF $h_{FE(1)}$

| | | |
|-------|---------|---------|
| Rank | O | Y |
| Range | 100-200 | 200-300 |